

| L<br>Number | Hits  | Search Text   | DB  | Time stamp          |
|-------------|-------|---|---|---------------------|
| 1           | 233   | (438/210).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2003/05/19<br>16:26 |
| 2           | 120   | ((438/210).CCLS.) and (sram or dram)  | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2003/05/19<br>16:27 |
| 3           | 77461 | (capacitor or dielectric) near5 substrate   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2003/05/19<br>16:28 |
| 4           | 61    | ((438/210).CCLS.) and (sram or dram))<br>and ((capacitor or dielectric) near5<br>substrate) | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT;<br>IBM_TDB | 2003/05/19<br>16:28 |